# **BLP15H9S30**

# **Power LDMOS transistor**

**AMPLEON** 

Rev. 4 — 12 January 2023

Product data sheet

# 1. Product profile

#### 1.1 General description

A 30 W LDMOS driver transistor for broadcast and industrial applications. The excellent ruggedness of this device makes it ideal for digital and analog transmitter applications in the frequency range from HF to 2 GHz.

Table 1. Typical performance

Test signal	f	V <sub>DS</sub>	$P_L$	Gp	ηD
	(MHz)	(V)	(W)	(dB)	(%)
pulsed RF	1400	50	30	22	63
CW	325 to 352	50	30	28	68
	360 to 450	50	30	17	60
	1025 to 1150	50	30	17	50

#### 1.2 Features and benefits

- Designed for broadband operation
- High efficiency
- Integrated dual sided ESD protection
- Excellent ruggedness
- High power gain
- Excellent reliability
- Easy power control
- Excellent stability
- For RoHS compliance see the product details on the Ampleon website

#### 1.3 Applications

- Broadcast transmitter applications
- Industrial, scientific and medical applications
- Applicable at frequencies from HF to 2 GHz

# 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	drain	Ž	
2	gate		1 
3	source	11 31	2 3 3 sym112

<sup>[1]</sup> Connected to flange.

# 3. Ordering information

Table 3. Ordering information

Package name	Orderable part number	12NC	<b>9</b> 1111 <b>1</b> 111	Min. orderable quantity (pieces)
TO-270-2F-1	BLP15H9S30Z	9349 602 51515	TR13; 500-fold; 24 mm; dry pack	500
	BLP15H9S30XY	9349 602 51538	TR7; 100-fold; 24 mm; dry pack	100

# 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage		-	106	V
$V_{GS}$	gate-source voltage		-6	+11	V
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature	[1]	-	225	°C

<sup>[1]</sup> Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

# 5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-c)</sub>	thermal resistance from junction to case	$T_{case} = 80  ^{\circ}\text{C};  V_{DS} = 50  \text{V}; \ P_{L} = 30  \text{W}$	1.9	K/W

# 6. Characteristics

#### Table 6. DC characteristics

 $T_i = 25$  °C; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.23 \text{ mA}$	106	-	-	V
V <sub>GS(th)</sub>	gate-source threshold voltage	$V_{DS} = 10 \text{ V}; I_D = 23 \text{ mA}$	1.5	2.0	2.5	V
$V_{GSq}$	gate-source quiescent voltage	$V_{DS} = 50 \text{ V}; I_{D} = 10 \text{ mA}$	1.5	2.0	2.5	V
I <sub>DSS</sub>	drain leakage current	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 50 V	-	-	1.4	μΑ
I <sub>DSX</sub>	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	3.9	-	А
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 11 V; V <sub>DS</sub> = 0 V	-	-	140	nA
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 805 \text{ mA}$	-	0.89	-	Ω

#### Table 7. RF characteristics

Test signal: pulsed RF;  $t_p = 100~\mu$ s;  $\delta = 20~\%$ ; f = 1400~MHz; RF performance at  $V_{DS} = 50~V$ ;  $I_{Dq} = 10~m$ A;  $T_{case} = 25~^{\circ}$ C; unless otherwise specified; in a class-AB production test circuit with Johnstech socket.

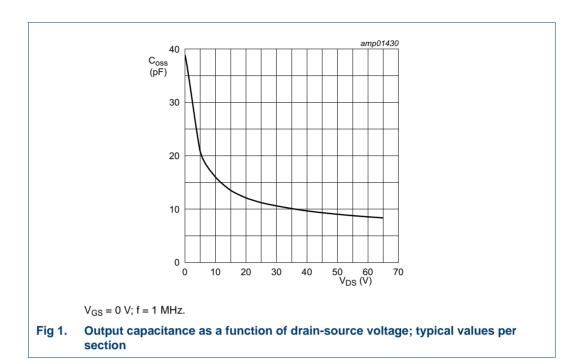
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	P <sub>L</sub> = 30 W	20.5	22	-	dB
RLin	input return loss	P <sub>L</sub> = 30 W	-	-10	-6	dB
$\eta_{D}$	drain efficiency	P <sub>L</sub> = 30 W	62	65	-	%

#### Table 8. AC characteristics

 $T_i = 25$  °C; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C <sub>iss</sub>	input capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$	-	26	-	рF
C <sub>oss</sub>	output capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$	-	9.2	-	рF
C <sub>rss</sub>	reverse transfer capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$	-	0.19	-	pF

**Power LDMOS transistor** 



# 7. Test information

### 7.1 Ruggedness in class-AB operation

The BLP15H9S30 is capable of withstanding a load mismatch corresponding to VSWR = 30 : 1 through all phases under the following conditions:  $V_{DS}$  = 55 V;  $I_{Dq}$  = 10 mA;  $P_L$  = 47 W; f = 1400 MHz; pulsed CW ( $t_p$  = 100  $\mu$ s;  $\delta$  = 20 %).

#### 7.2 Test circuit

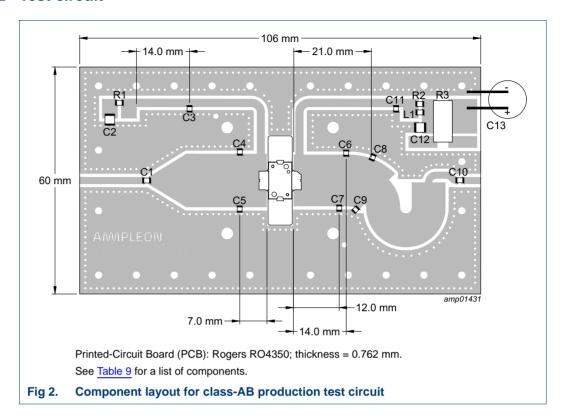


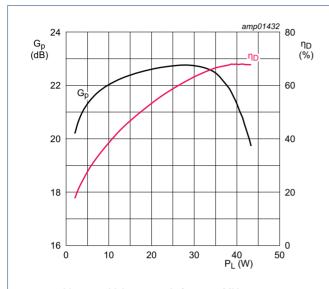
Table 9. List of components For test circuit see Figure 2.

Component Description Value Remarks [1] C1 4.7 pF multilayer ceramic chip capacitor C2, C12 multilayer ceramic chip capacitor  $4.7 \mu F$ , 100 VC3, C11 30 pF [1] multilayer ceramic chip capacitor [1] C4, C5 multilayer ceramic chip capacitor 3.6 pF [1] C6, C7 multilayer ceramic chip capacitor 4.7 pF C8, C9 multilayer ceramic chip capacitor [1] 6.2 pF C10 multilayer ceramic chip capacitor [1] 30 pF C13 470 μF, 64 V electrolytic capacitor R1 chip resistor 4.7 Ω SMD 1206 R2 chip resistor  $10 \Omega$ SMD 1206 R3 shunt resistor  $0.01~\Omega$ L1 9 nH inductor Coilcraft: 1508-9N0GLB

[1] American Technical Ceramics type 800A or capacitor of same quality.

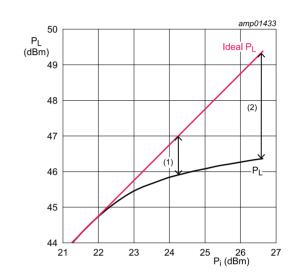
### 7.3 Graphical data

#### 7.3.1 Pulsed CW performance measured in production RF test circuit



 $V_{DS}$  = 50 V;  $I_{Dq}$  =10 mA; f = 1400 MHz;  $t_p$  = 100  $\mu s;$   $\delta$  = 20 %.

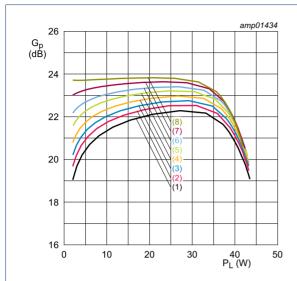
Fig 3. Power gain and drain efficiency as function of output power; typical values



 $V_{DS}$  = 50 V;  $I_{Dq}$  = 10 mA; f = 1400 MHz;  $t_p$  = 100  $\mu s;$   $\delta$  = 20 %.

- (1)  $P_{L(1dB)} = 45.9 \text{ dBm } (39 \text{ W})$
- (2)  $P_{L(3dB)} = 46.4 \text{ dBm } (43 \text{ W})$

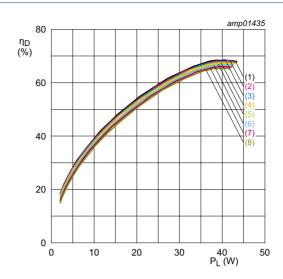
Fig 4. Output power as a function of input power; typical values



 $V_{DS}$  = 50 V; f = 1400 MHz;  $t_p$  = 100  $\mu s;$   $\delta$  = 20 %.

- (1)  $I_{Dq} = 2 \text{ mA}$
- (2)  $I_{Dq} = 5 \text{ mA}$
- (3)  $I_{Dq} = 10 \text{ mA}$
- (4)  $I_{Dq} = 20 \text{ mA}$
- (5)  $I_{Dq} = 40 \text{ mA}$
- (6)  $I_{Dq} = 60 \text{ mA}$
- (7)  $I_{Dq} = 100 \text{ mA}$
- (8)  $I_{Dq} = 140 \text{ mA}$

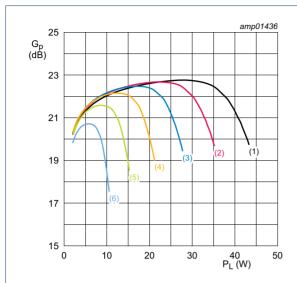
Fig 5. Power gain as a function of output power; typical values



 $V_{DS}$  = 50 V; f = 1400 MHz;  $t_p$  = 100  $\mu s; \, \delta$  = 20 %.

- (1)  $I_{Dq} = 2 \text{ mA}$
- (2)  $I_{Dq} = 5 \text{ mA}$
- (3)  $I_{Dq} = 10 \text{ mA}$
- (4)  $I_{Dq} = 20 \text{ mA}$
- (5)  $I_{Dq} = 40 \text{ mA}$
- (6)  $I_{Dq} = 60 \text{ mA}$
- (7)  $I_{Dq} = 100 \text{ mA}$
- (8)  $I_{Dq} = 140 \text{ mA}$

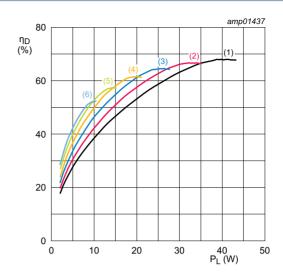
Fig 6. Drain efficiency as a function of output power; typical values



 $I_{Dq}$  = 10 mA; f = 1400 MHz;  $t_p$  = 100  $\mu s;$   $\delta$  = 20 %.

- (1)  $V_{DS} = 50 \text{ V}$
- (2)  $V_{DS} = 45 \text{ V}$
- (3)  $V_{DS} = 40 \text{ V}$
- (4)  $V_{DS} = 35 \text{ V}$
- (5)  $V_{DS} = 30 \text{ V}$
- (6)  $V_{DS} = 25 \text{ V}$

Fig 7. Power gain as a function of output power; typical values



 $I_{Dq}$  = 10 mA; f = 1400 MHz;  $t_p$  = 100  $\mu$ s;  $\delta$  = 20 %.

- (1)  $V_{DS} = 50 \text{ V}$
- (2)  $V_{DS} = 45 \text{ V}$
- (3)  $V_{DS} = 40 \text{ V}$
- (4)  $V_{DS} = 35 \text{ V}$
- (5)  $V_{DS} = 30 \text{ V}$
- (6)  $V_{DS} = 25 \text{ V}$

Fig 8. Drain efficiency as a function of output power; typical values

# 8. Package outline

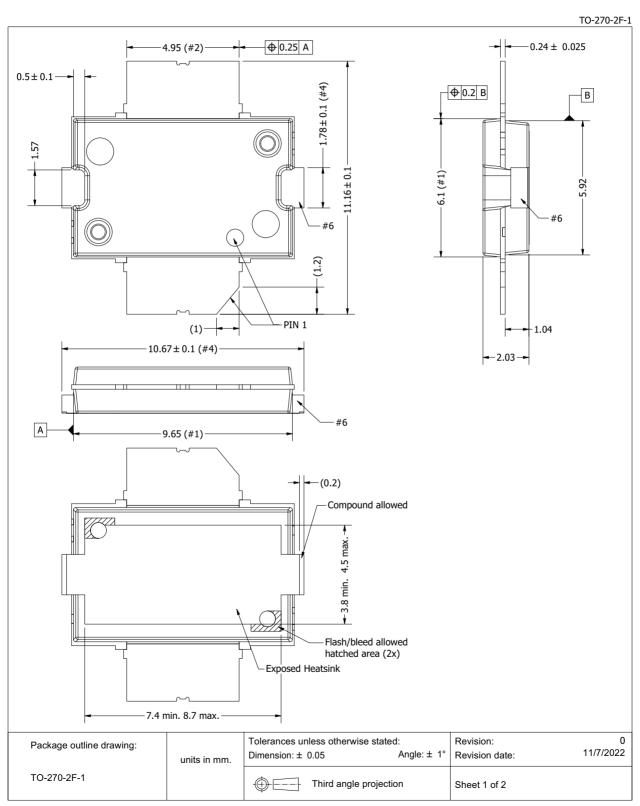


Fig 9. Package outline TO-270-2F-1 (sheet 1 of 2)

BLP15H9S30

TO-270-2F-1

Drawing Notes				
Items	Description			
(4)	Dimensions are excluding mold protrusion. The mold protrusion is maximum 0.15 mm per side. See also detail B.			
(1)	In the dambar area max. protrusion is 0.55 mm. max. in length and 0.3 mm. max. in width (4x). See also detail B.			
(2)	The lead dambar (metal) protrusions are not included. Add 0.14 mm max to the total lead dimension at the dambar location			
(3)	The leads and exposed heatsink are plated with matte Tin (Sn).			
(4)	Dimensions (Heatsink ears) 10,67 and 1,78 do not include mouldprotrusion. Overall Max. dimensions incl. mould			
(4)	protrusions is 10.92 mm. (max.) and 2.03 mm. (max.).			
(5)	Lead coplanarity over the leads is 0,1 mm. maximum.			
(6)	Surfaces may remain unplated (not solderable surfaces).			

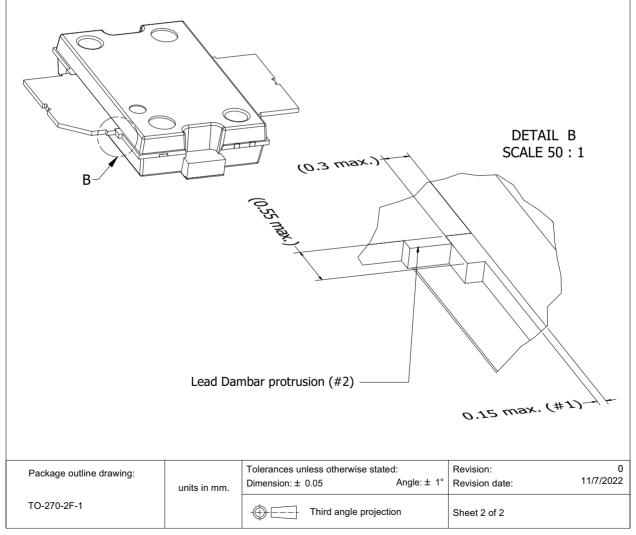


Fig 10. Package outline TO-270-2F-1 (sheet 2 of 2)

# 9. Handling information

#### **CAUTION**



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 10. ESD sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C2B [1]
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	2 [2]

- [1] CDM classification C2B is granted to any part that passes after exposure to an ESD pulse of 750 V.
- [2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V.

#### 10. Abbreviations

Table 11. Abbreviations

Acronym	Description
CW	Continuous Wave
ESD	ElectroStatic Discharge
HF	High Frequency
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MTF	Median Time to Failure
RoHS	Restriction of Hazardous Substances
SMD	Surface Mounted Device
VSWR	Voltage Standing Wave Ratio

# 11. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
BLP15H9S30 v.4	20230112	Product data sheet	-	BLP15H9S30 v.3		
Modifications:	Table 3 on page 2: package name changed from SOT1482-1 to TO-270-2F-1					
	<ul> <li><u>Table 5 on page 2</u>: value changed from 2.2 K/W to 1.9 K/W</li> </ul>					
	<ul> <li>Section 8 on</li> </ul>	page 9: package outline dra	awing changed from SO	T1482-1 to TO-270-2F-1		
	<ul> <li>Section 12 o</li> </ul>	n page 12: updated section				
BLP15H9S30 v.3	20210708	Product data sheet	-	BLP15H9S30 v.2		
BLP15H9S30 v.2	20201210	Product data sheet	-	BLP15H9S30 v.1		
BLP15H9S30 v.1	20200807	Product data sheet	-	-		

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#### 12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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# **BLP15H9S30**

#### **Power LDMOS transistor**

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